

60 AMP PRESS FIT HIGH VOLTAGE DIODES (GPP DIE)

FEATURES

- VOID FREE VACUUM DIE SOLDERING For Maximum Mechanical Strength And Heat Dissipation (Solder Voids: Typical ≤ 2%, Max. ≤ 5% of Die Area)
- Full Silicon Die Area on P- and N-Sides Are Soldered to Copper Slugs For Minimum Stress And Maximum Heat Dissipation
- Press Fit Into Heat Sink to Further Enhance Heat Handling Capability
- Very Low Resistivity Silicon Die For Lower Operating Junction Temperature
- Very Low Reverse Current Leakage For Minimum Energy Loss

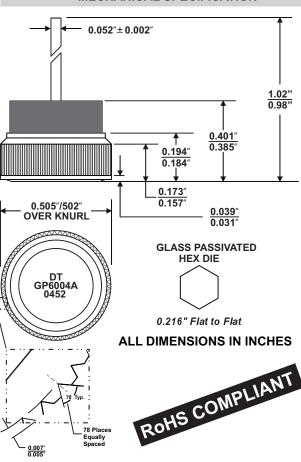
MECHANICAL DATA

- Case: Nickel plated copper
- Finish: All external surfaces are corrosion resistant and the contact areas are readily weldable or solderable
- Maximum Soldering Temperature: 250 °C, 0.25" from case for 10 Seconds
- Mounting Position: Any. Maximum force used for diode insertion to be 12 KN
- Polarity: Color coded epoxy ring-ANODE on LEAD (Beige Ring): Part No.=GP6002PFA/GP6004PFA. CATHODE on LEAD (Black Ring) Part No.=GP6002PFC/GP6004PFC. Part No. marked on cap base.

MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

PARAMETER (TEST CONDITIONS)		SYMBOL	RATINGS		UNITS	
Series Number			GP6002PFA GP6002PFC	GP6004PFA GP6004PFC		
Maximum Recurrent Peak Reverse V	oltage	VRRM				
Working Peak Reverse Voltage		VRWM	200	400		
Maximum DC Blocking Voltage		VDC			VOLTS	
Non-Repetitive Peak Reverse Voltage	e (Half Wave, 60 Hz, Single Phase)	Vrsm	240	480		
Average Forward Rectified Current	-	lo	60	60		
Non-repetitive Peak Forward Surge ((Half wave, single phase, 60 Hz sine		IFSM	800	800	AMPS	
Forward VoltageDrop	@ 60Amp DC (Typical) @ 100Amp DC (Typical)	VF	<1.05 <1.15	<1.05 <1.15	VOLTS	
Maximum DC Reverse Current at Rated Blocking Voltage Tc = 25 $^{\circ}$ C)		İR	<1.0	<1.0	μ Ά	
Junction Operating & Storage Temperature Range		TJ,TSTG	-65 to +200	-65 to +200	°C	



MECHANICAL SPECIFICATION